

Modeling Directed Self-Assembly of Block Copolymers for Lithographic applications

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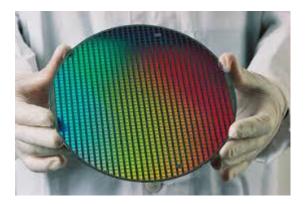
leti Outline

The DSA technology for nano patterning

Modeling with Comsol phase field interface

Some results & applications

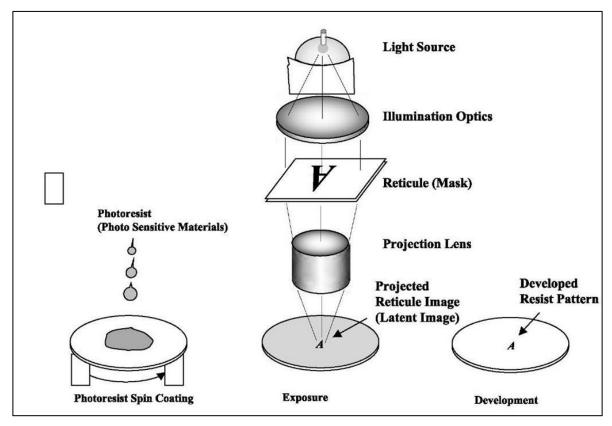
Leti Context



A full silicium patterned wafer

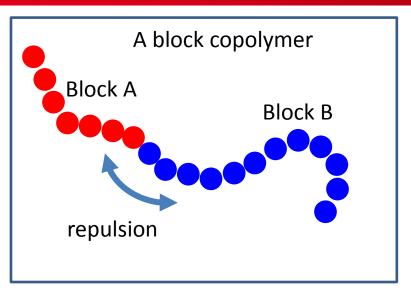
Limitations of conventional optical lithography due to resolution (λ=193nm)

Nano patterning for chip fabrication → Lithography step



Optical lithography: principle schematic

Leti DSA technology principle



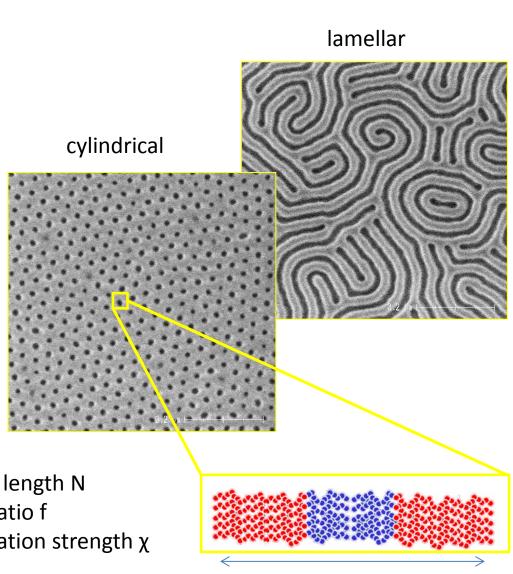
Annealing → Selfassembly in ordered 2phases structures

Change morphology by tuning material's properties

chain's length N

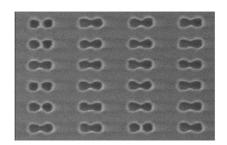
Block ratio f

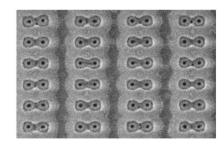
Segregation strength x

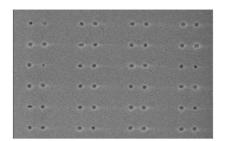


Leti DSA by grapho-epitaxy

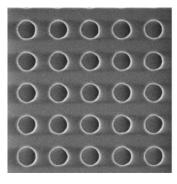
« Contact doubling »

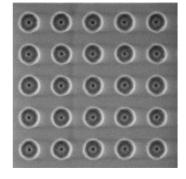


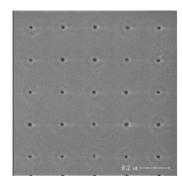




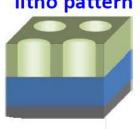
« Contact shrink »

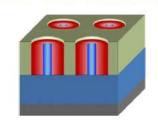






193nm or e-beam litho pattern





BCP self-assembly





Leti Modeling of DSA

- Purpose:
 - Metrology not sufficient (lack of resolution)
 - Development cost
- Requirements:
 - Good runtime, especially for 3D for parametric studies
 - Proper boundary conditions for dealing w/ interfaces
- Choice of the model:
 - not atomistic or particle model (too slow)
 - phase field model :
 - describe system through order parameter

Leti Comsol phase field interface

- Cahn-Hilliard equation
 - → phase separation of a binary mixture
- Free energy

$$E = \int_{\Omega} \left(\frac{\phi^4}{4} - \frac{\phi^2}{2} \right) d\mathbf{r} - \int_{\Omega} \epsilon^2 ||\nabla \phi||^2 d\mathbf{r} + \int_{\Omega} \int_{\Omega} \alpha (\phi(\mathbf{r}) - \phi_0) (\phi(\mathbf{r}') - \phi_0) G(\mathbf{r}, \mathbf{r}') d\mathbf{r}' d\mathbf{r} \right)$$

Mixing energy

Interfacial energy

Long range interactions



Added in weak formulation

Comsol phase field interface

Fick's law

$$\frac{\partial \phi}{\partial t} = \Delta \mu \qquad \text{with} \quad \mu = \frac{\delta E}{\delta \phi} \quad \text{the chemical potential}$$

• Finally $\frac{\partial \phi}{\partial t} = \Delta \left(\phi^3 - \phi - \epsilon^2 \Delta \phi\right) - \alpha (\phi - \phi_0)$

$$\mathbf{n}.\nabla\mu=0$$

$$\mathbf{n}.\nabla\phi = -\cos\theta$$

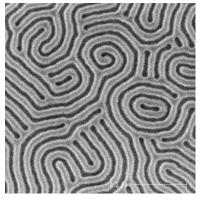
Contact angle

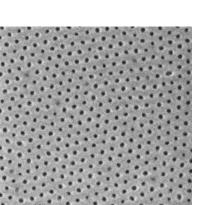
• Initial conditions : small fluctuations around $\phi_{\scriptscriptstyle \Omega}$

Leti Simulation VS experimental data

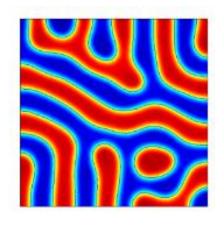
Free surface simulations

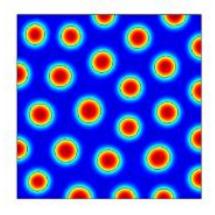
SEM images



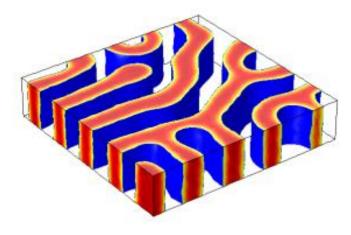


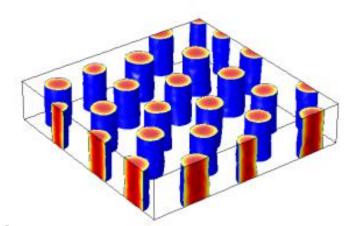
2D





3D

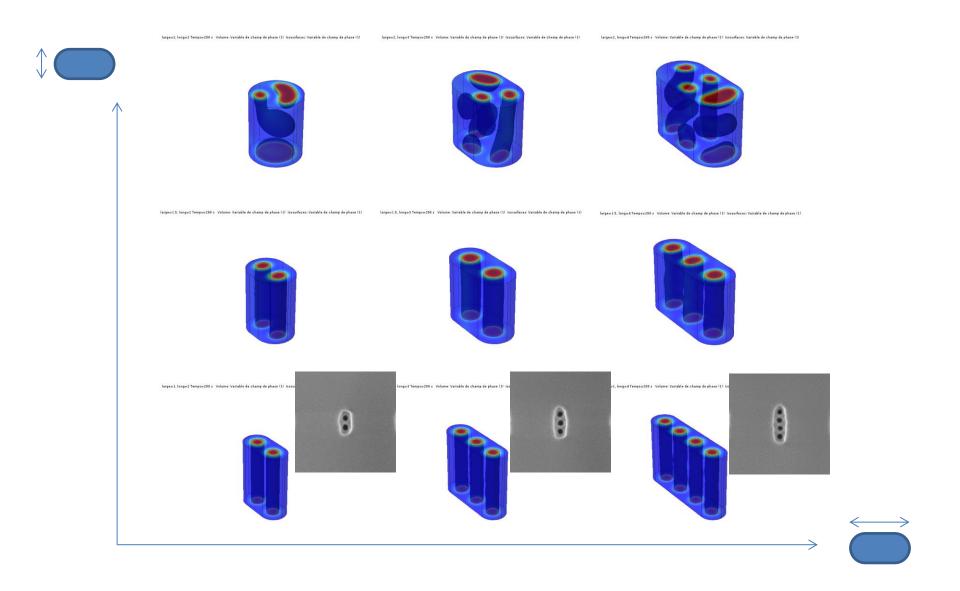






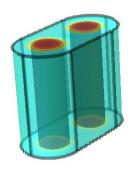
Good agreement!

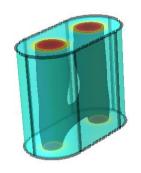
Leti Guide's commensurability

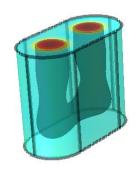


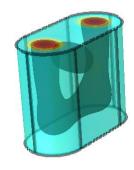
Leti Affinity impact

By changing contact angle θ we can change the affinity of interfaces









neutral

Preferential affinity

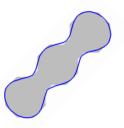


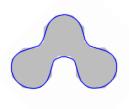
Study impact of a different surface energy

Leti Contact multiplication

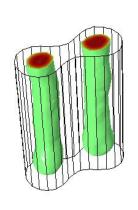
OPC simulated patterns

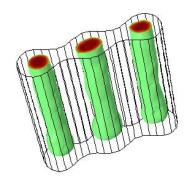






Corresponding 3D simulations









Pattern optimization

Leti Summary

Good qualitative agreement



Comsol phase field interace is suitable for modeling DSA

- Perspectives
 - Full Calibration
 - More interesting studies!